

Thursday 20 November

13:30

LGAD

Session | Location: CERN, 4/3-006 - TH Conference Room | Conveners: Virginia Greco, Hartmut Sadrozinski

13:30-13:50 Bulk defect investigations for proton irradiated sensors

Speaker

Alexandra Junkes

13:50-14:10 The new IRRAD facility at CERN

Speaker

Maurice Glaser

14:10-14:30

Study of Low-dose Radiation Resistance of Sidewall Passivation on p-type SCP Devices

Speaker

Vitaliy Fadeyev

14:30-14:50

Long-term HV stability of the collected charge in charge multiplication sensors

Speakers

Christopher Betancourt, Susanne Kuehn

14:50-15:10 Effects of irradiation on LGAD devices with high excess current

Speaker

Gregor Kramberger

15:10-15:30 Measurements on segmented LGAD devices

Speaker

Emanuele Cavallaro

15:30-16:00 **Coffee**

16:00-16:20 Measurements on thin LGAD Sensors

Speaker

Hartmut Sadrozinski

16:20-16:40 Design and Fabrication of an Optimal Peripheral Region for the LGAD

Speaker

Dr Pablo Fernández-Martínez

16:40-17:00 First results on the timing resolution properties of LGAD

Speaker

Mr Nicolo Cartiglia

17:00-17:30 Discussion on LGAD and Fast Timing

Speaker
Virginia Greco

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